2N918

NPN SILICON RF TRANSISTOR



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N918 type is an NPN silicon RF transistor, manufactured by the epitaxial planar process and designed for high frequency amplifier and oscillator applications.

MARKING: FULL PART NUMBER



MAXIMUM	RATINGS: (T _A =25°C unless otherwis	se noted)		
	. //	SYMBOL		UNITS
Collector-B	ase Voltage	V_{CBO}	30	V
Collector-E	mitter Voltage	V_{CEO}	15	V
Emitter-Bas	se Voltage	V_{EBO}	3.0	V
Continuous Collector Current		IC	50	mA
Power Dissipation		P_{D}	200	mW
Power Dissipation (T _C =25°C)		P_{D}	300	mW
Operating and Storage Junction Temperature		T _J , T _{stg}	-65 to +200	°C
Thermal Resistance		$\Theta_{\sf JA}$	87.5	°C/W
Thermal Resistance		Θ JC	58.3	°C/W
ELECTRIC	AL CHARACTERISTICS: (TA=25°C t	unless otherwise no	oted)	
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
ICBO	V _{CB} =15V		10	nA
I _{CBO}	V _{CB} =15V, T _A =150°C		1.0	μΑ
BV_{CBO}	I _C =1.0μA	30		V
BVCEO	I _C =3.0mA	15		V
BV_{EBO}	I _E =10μA	3.0		V
17	I -40 A I -4 0 A		0.4	1/

I _{CBO}	V _{CB} =15V, T _A =150°C		1.0	μΑ
BV _{CBO}	I _C =1.0μA	30		V
BVCEO	I _C =3.0mA	15		V
BV _{EBO}	I _E =10μA	3.0		V
VCE(SAT)	I _C =10mA, I _B =1.0mA		0.4	V
V _{BE} (SAT)	I _C =10mA, I _B =1.0mA		1.0	V
h _{FE}	V _{CE} =1.0V, I _C =3.0mA	20		
f_{T}	V_{CE} =10V, I_{C} =4.0mA, f=100MHz	600		MHz
C_{ob}	V_{CB} =10V, I_E =0, f=1.0MHz		1.7	pF
C_{ob}	V_{EB} =0, I_E =0, f=1.0MHz		3.0	pF
c_{ib}	V_{EB} =0.5V, I_{C} =0, f=1.0MHz		2.0	pF
P_0	V_{CB} =15V, I_{C} =8.0mA, f=500MHz	30		mW
G _{pe}	V_{CB} =12V, I_{C} =6.0mA, f=200MHz	15		dB
η	V_{CB} =15V, I_{C} =8.0mA, f=500MHz	25		%
NF	V _{CE} =6.0V, I _C =1.0mA,			
	R_G =400 Ω , f=60kHz		6.0	dB

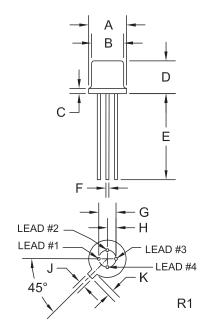
R1 (11-September 2012)

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TO-72 CASE - MECHANICAL OUTLINE



DIMENSIONS								
	INCHES		MILLIMETERS					
SYMBOL	MIN	MAX	MIN	MAX				
A (DIA)	0.209	0.230	5.31	5.84				
B (DIA)	0.175	0.195	4.45	4.95				
С	-	0.030	-	0.76				
D	0.170	0.210	4.32	5.33				
Е	0.500	-	12.70	-				
F (DIA)	0.016	0.019	0.41	0.48				
G (DIA)	0.100		2.54					
Н	0.050		1.27					
J	0.036	0.046	0.91	1.17				
K	0.028	0.048	0.71	1.22				

TO-72 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector 4) Case

MARKING: FULL PART NUMBER

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- PbSn plating options
- · Package details
- · Application notes
- · Application and design sample kits
- Custom product and package development

CONTACT US

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